

INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Substitute for form 1449/PTO)		ATTY. DOCKET NO. 057810-0088		SERIAL NO. 10/790,759			
		APPLICANT Eiji MARUYAMA					
		FILING DATE March 03, 2004		GROUP 1795			
U.S. PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code ₂ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		US					
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FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Codes-Number 4-Kind Codes (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation Yes No	
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
		M. SASAKI et al., "Effects of SR Irradiation on tin-doped indium oxide thin film prepared by rf magnetron sputtering," REVIEW OF SCIENTIFIC INSTRUMENTS, AIP, MELVILLE, NY, US, Vol. 73, No. 3, 1 March 2002, pages 1384-1386, XP012039842					
		European Examination Report issued in European Patent Application No. EP 04 251 457.0 dated March 3, 2010					
EXAMINER				DATE CONSIDERED			

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